3-TO-8 LINE DECODER/DEMULTIPLEXER

FEATURES

- Demultiplexing capability
- Multiple input enable for easy expansion
- Ideal for memory chip select decoding
- Active HIGH mutually exclusive outputs
- Output capability: standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT238 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT238 decoders accept three binary weighted address inputs (A_0, A_1, A_2) and when enabled, provide 8 mutually exclusive active HIGH outputs (Y_0 to Y_7).
The "238" features three enable inputs: two active LOW ($\overline{E}_1$ and $\overline{E}_2$) and one active HIGH (E_3). Every output will be LOW unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH.

This multiple enable function allows easy parallel expansion of the "238" to a 1-of-32 (5 lines to 32 lines) decoder with just four "238" ICs and one inverter.

The "238" can be used as an eight output demultiplexer by using one of the active LOW enable inputs as the data input and the remaining enable inputs as strobes. Unused enable inputs must be permanently tied to their appropriate active HIGH or LOW state.

The "238" is identical to the "138" but has non-inverting outputs.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay A_n to Y_n E_3 to Y_n $\overline{E}_n$ to Y_n	C_L = 15 pF V_{CC} = 5 V	14 16 17	18 20 21	ns ns ns
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per package	notes 1 and 2	72	76	pF

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in µW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
   f_i = input frequency in MHz
   f_o = output frequency in MHz
   $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs
   C_L = output load capacitance in pF
   V_{CC} = supply voltage in V
2. For HC the condition is V_I = GND to V_{CC}
   For HCT the condition is V_I = GND to V_{CC} − 1.5 V

PACKAGE OUTLINES

SEE PACKAGE INFORMATION SECTION

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3	A_0 to A_2	address inputs
4, 5	$\overline{E}_1$, $\overline{E}_2$	enable inputs (active LOW)
6	E_3	enable input (active HIGH)
8	GND	ground (0 V)
15, 14, 13, 12 11, 10, 9, 7	Y_0 to Y_7	outputs (active HIGH)
16	V_{CC}	positive supply voltage

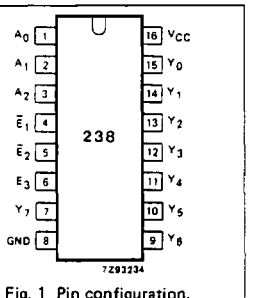


Fig. 1 Pin configuration.

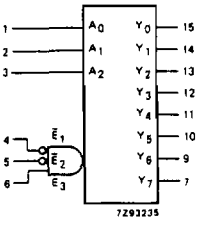
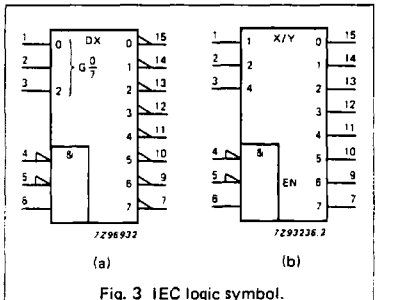


Fig. 2 Logic symbol.



(a) (b)

Fig. 3 IEC logic symbol.

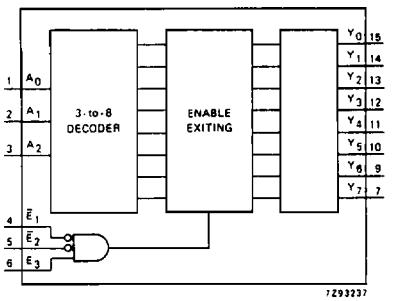


Fig. 4 Functional diagram.

FUNCTION TABLE

INPUTS						OUTPUTS							
$\bar{E}_1$	$\bar{E}_2$	E_3	A_0	A_1	A_2	Y_0	Y_1	Y_2	Y_3	Y_4	Y_5	Y_6	Y_7
H	X	X	X	X	X	L	L	L	L	L	L	L	L
X	H	X	X	X	X	L	L	L	L	L	L	L	L
X	X	L	X	X	X	L	L	L	L	L	L	L	L
L	L	H	L	L	L	H	L	L	L	L	L	L	L
L	L	H	H	L	L	L	H	L	L	L	L	L	L
L	L	H	L	H	L	L	L	H	L	L	L	L	L
L	L	H	H	H	L	L	L	L	H	L	L	L	L
L	L	H	L	L	H	L	L	L	L	H	L	L	L
L	L	H	H	L	H	L	L	L	L	L	H	L	L
L	L	H	L	H	H	L	L	L	L	L	L	H	L
L	L	H	H	H	H	L	L	L	L	L	L	L	H

H = HIGH voltage level
L = LOW voltage level
X = don't care

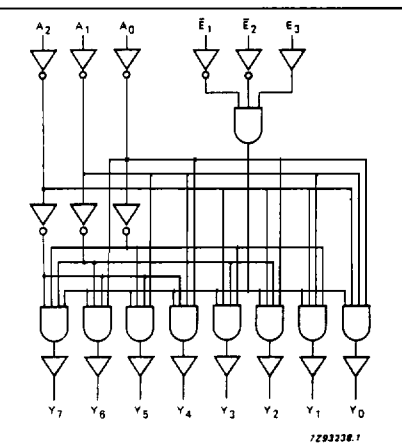


Fig. 5 Logic diagram.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard
I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/t_{PLH}	propagation delay A_n to Y_n		47 17 14	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 6
t_{PHL}/t_{PLH}	propagation delay E_3 to Y_n		52 19 15	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig. 6
t_{PHL}/t_{PLH}	propagation delay $\overline{E}_n$ to Y_n		50 18 14	155 31 26		195 39 33		235 47 40	ns	2.0 4.5 6.0	Fig. 7
t_{THL}/t_{TLH}	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Figs 6 and 7

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A_n	0.70
$\overline{E}_n$	0.40
E_3	1.45

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}	propagation delay A_n to Y_n		21	35		44		53	ns	4.5	Fig. 6
t_{PLH}	propagation delay A_n to Y_n		17	35		44		53	ns	4.5	Fig. 6
t_{PHL}	propagation delay E_3 to Y_n		22	37		46		56	ns	4.5	Fig. 6
t_{PLH}	propagation delay E_3 to Y_n		18	37		46		56	ns	4.5	Fig. 6
t_{PHL}	propagation delay $\overline{E}_n$ to Y_n		21	35		44		53	ns	4.5	Fig. 7
t_{PLH}	propagation delay $\overline{E}_n$ to Y_n		18	35		44		53	ns	4.5	Fig. 7
t_{THL}/ t_{TLH}	output transition time		7	15		19		22	ns	4.5	Figs 6 and 7

AC WAVEFORMS

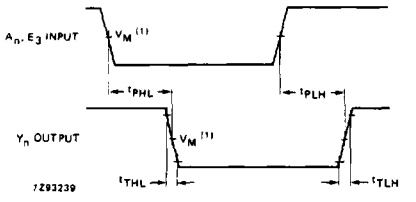


Fig. 6 Waveforms showing the address input (A_n) and enable input (E_3) to output (Y_n) propagation delays and the output transition times.

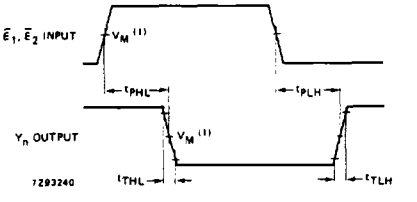


Fig. 7 Waveforms showing the enable input ($\overline{E}_n$) to output (Y_n) propagation delays and the output transition times.

Note to AC waveforms

(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.